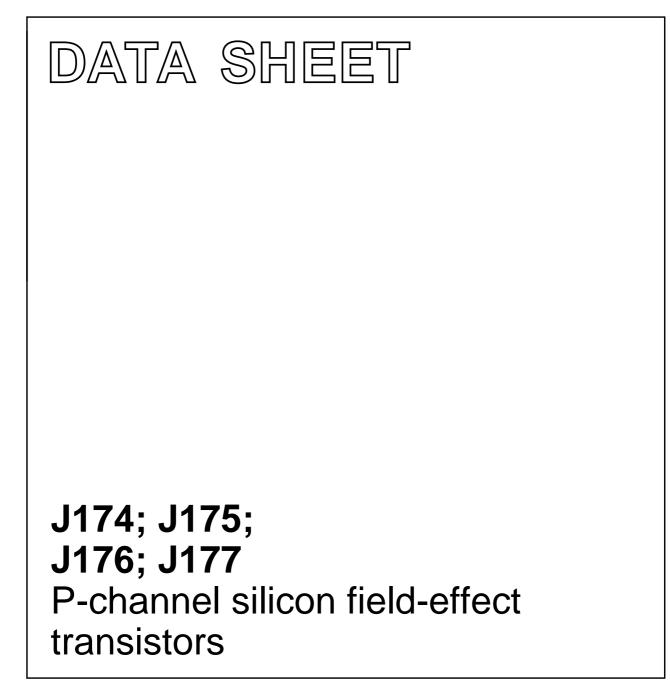
DISCRETE SEMICONDUCTORS



Product specification File under Discrete Semiconductors, SC07 April 1995



DESCRIPTION

Silicon symmetrical p-channel junction FETs in a plastic TO-92 envelope and intended for application with analog switches, choppers, commutators etc.

A special feature is the interchangeability of the drain and source connections.

PINNING

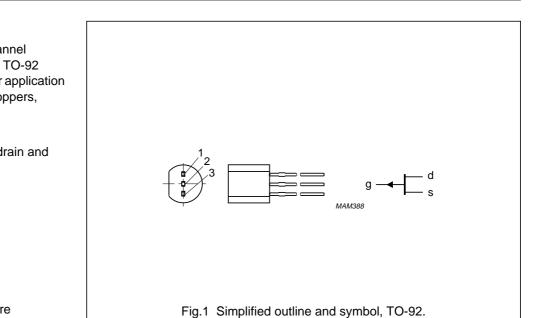
1 = source

- 2 = gate
- 3 = drain

Note: Drain and source are interchangeable.

QUICK REFERENCE DATA

Drain-source voltage	$\pm V_{\text{DS}}$	max.		30			V
Gate-source voltage	V _{GSO}	max.	30				V
Gate current	$-I_G$	max.	50				mA
Total power dissipation							
up to $T_{amb} = 50 \ ^{\circ}C$	P _{tot}	max.	400				mW
			J174	J175	J176	J177	
Drain current				_			
$-V_{DS} = 15 \text{ V}; V_{GS} = 0$	-I _{DSS}	min.	20	7	2	1.5	mA
103 = 101, $103 = 0$.032	max.	135	70	35	20	mA
Drain-source ON-resistance							
$-V_{DS} = 0.1 V; V_{GS} = 0$	R_{DSon}	max.	85	125	250	300	Ω



Product specification

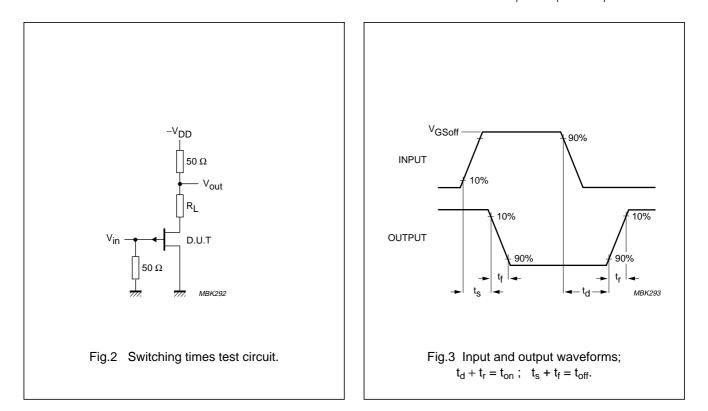
P-channel silicon field-effect transistors				J174; J175; J176; J177				
RATINGS								
Limiting values in accordance with the Absolute Maximur	n System (IEC	34)						
Drain-source voltage	$\pm V_{D}$	os	max.		30		V	
Gate-source voltage	V _{GS}	0	max.		30		V	
Gate-drain voltage			max.		30		V	
Gate current (DC)			max.		50		mA	
Total power dissipation								
up to T _{amb} = 50 °C	P _{tot}		max.	400			mW	
Storage temperature range	T _{stg}			-6	-65 to +150		О° С	
Junction temperature	Tj	0		max.			°C	
THERMAL RESISTANCE								
From junction to ambient in free air	R _{th}	j-a	=		250		K/W	
STATIC CHARACTERISTICS								
T _i = 25 °C unless otherwise specified			J174	J175	J176	J177		
Gate cut-off current							-	
$V_{GS} = 20 V; V_{DS} = 0$	I _{GSS}	max.	1	1	1	1	nA	
Drain cut-off current								
–V _{DS} = 15 V; V _{GS} = 10 V	-I _{DSX}	max.	1	1	1	1	nA	
Drain current								
		min.	20	7	2	1.5	mA	
$-V_{DS} = 15 \text{ V}; V_{GS} = 10 \text{ V}$	-I _{DSS}	max.	135	70	35	20	mA	
Gate-source breakdown voltage								
$I_{G} = 1 \ \mu A; \ V_{DS} = 0$	V _{(BR)GSS}	min.	30	30	30	30	V	
Gate-source cut-off voltage								
$-I_D = 10 \text{ nA}; V_{DS} = -15 \text{ V}$	V _{GS off}	min.	5	3	1	0.8		
Drain aguras ON registeras		max.	10	6	4	2.25	v	
Drain-source ON-resistance -V _{DS} = 0.1 V; V _{GS} = 0	R _{DSon}	max.	85	125	250	300	Ω	

J174; J175; J176; J177

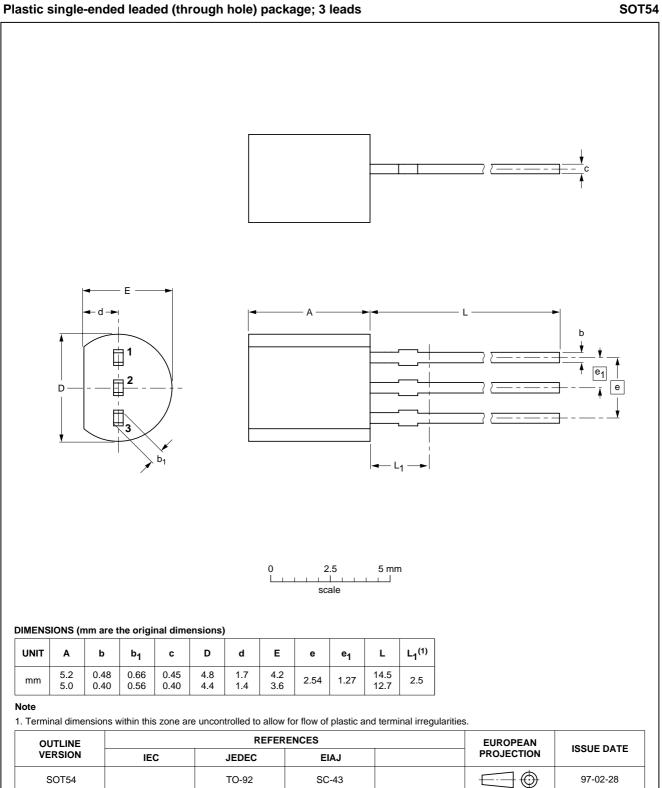
DYNAMIC CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$ unless otherwise specified

Input capacitance, f = 1 MHz							
$V_{GS} = 10 \text{ V}; V_{DS} = 0 \text{ V}$	C _{is}	typ.		8			pF
$V_{GS} = V_{DS} = 0$	C _{is}	typ.		30			pF
Feedback capacitance, f = 1 MHz							
$V_{GS} = 10 \text{ V}; V_{DS} = 0 \text{ V}$	C _{rs}	typ.		4			pF
Switching times (see Fig.2 + 3)			J174	J175	J176	J177	
Delay time	t _d	typ.	2	5	15	20	ns
Rise time	t _r	typ.	5	10	20	25	ns
Turn-on time	t _{on}	typ.	7	15	35	45	ns
Storage time	t _s	typ.	5	10	15	20	ns
Fall time	t _f	typ.	10	20	20	25	ns
Turn-off time	t _{off}	typ.	15	30	35	45	ns
Test conditions:	$-V_{DD}$		10	6	6	6	V
	V _{GS off}		12	8	6	3	V
	RL		560	1200	2000	2900	Ω
	$V_{GS \text{ on}}$		0	0	0	0	V



PACKAGE OUTLINE



J174; J175;

J176; J177

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J174; J175; J176; J177

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Short-form specification	The data in this specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.